

PHOTON IS OUR BUSINESS

Photo IC diodes



S7183 S7184

Linear current amplification of photodiode output

The S7183 and S7184 consist of a photodiode and a signal processing circuit for amplifying the photocurrent generated from the photodiode up to 1300 times. Despite a small active area, these photo ICs provide an output nearly equal to that from photodiodes with a 20×20 mm active area. Both S7183 and S7184 can be used the same way as a reverse-biased photodiode, and in most cases, they deliver a sufficient output voltage by just connecting a load resistor.

Features

- Clear plastic package
- Operation just as easy as using photodiodes
- Large output current rivaling that of a phototransistor
- Good linearity

Applications

- Energy saving sensors for TV brightness controls, etc.
- Light dimmers for liquid crystal panels
- Various types of light level measurement

→ Absolute maximum ratings (Ta=25 °C)

Parameter		Symbol	Condition	Value	Unit
Reverse voltage		VR		-0.5 to +16	٧
Photocurrent		IL	10		mA
Forward current		IF	10		mA
Power dissipation*1		Р	250		mW
Operating temperature		Topr	No dew condensation*2	v condensation*2 -30 to +80	
Storage temperature		Tstg	No dew condensation*2	dew condensation*2 -40 to +85	
Soldering	S7183			260 °C, 3 s, at least 2.5 mm away from package surface	-
	S7184	_		350 °C, 3 s	-

Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

= Electrical and optical characteristics (Ta=25 °C)

Parameter	Symbol	Condition		Min.	Тур.	Max.	Unit
Spectral response range	λ			-	300 to 1000	-	nm
Peak sensitivity wavelength	λр			-	650	-	nm
Operating reverse voltage	VR			3	-	12	V
Dark current	ark current ID VR=5 V			-	0.5	10	nA
Photocurrent	IL	VR=5 V	S7183, 100 lx	0.75	1.0	1.25	mA
Filotocurrent		2856 K	S7184, 1000 lx	1.4	1.8	2.2	IIIA
Rise/fall times	tr, tf	10 to 90%,*3 $V_R=5$ V, $R_L=10$ kΩ $\lambda=660$ nm		-	0.6	-	ms

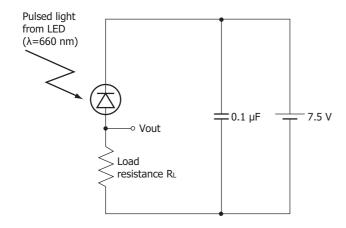
^{*3:} Rise/fall time measurement method: Refer to P.2.

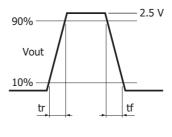
These products do not support lead-free soldering. For details on reflow soldering conditions for surface mount types, please contact our sales office.

^{*1:} Power dissipation decreases at a rate of 3.3 mW/°C above Ta=25 °C

^{*2:} When there is a temperature difference between a product and the surrounding area in high humidity environment, dew condensation may occur on the product surface. Dew condensation on the product may cause deterioration in characteristics and reliability.

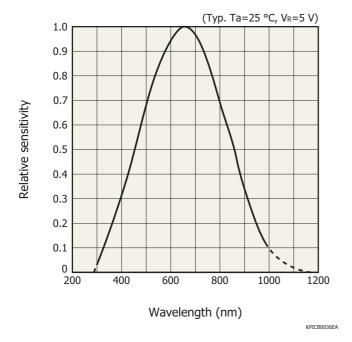
Rise/fall time measurement method



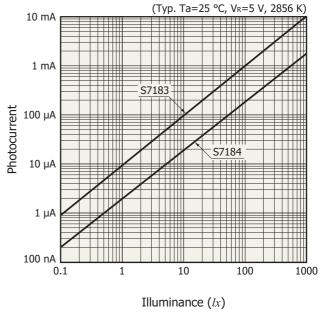


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- Spectral response

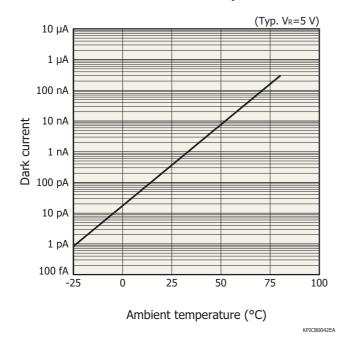


Linearity

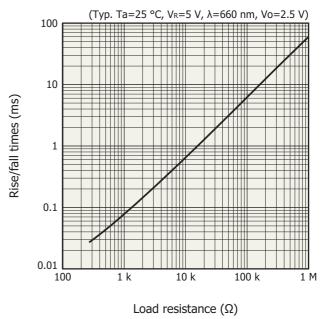


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- Dark current vs. ambient temperature

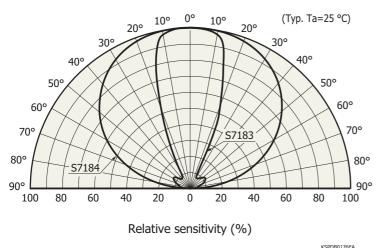


- Rise/fall times vs. load resistance



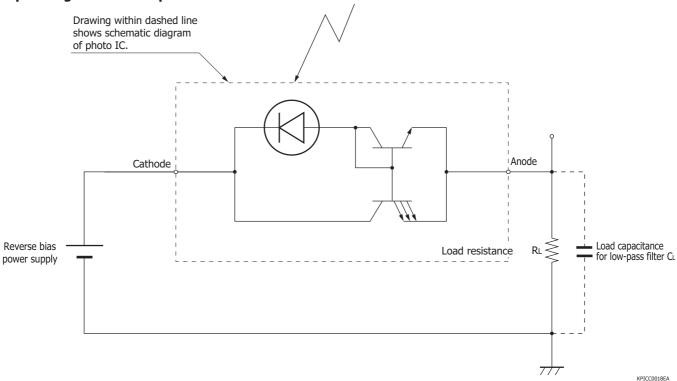
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Directivity





Operating circuit example

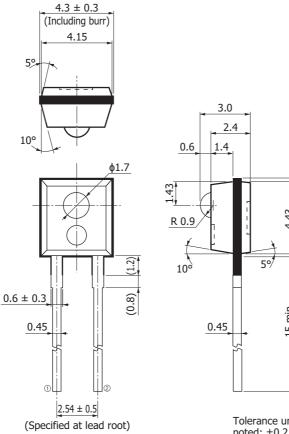


The photodiode must be reverse-biased so that a positive potential is applied to the cathode. To eliminate high-frequency components, we recommend placing a load capacitance CL in parallel with load resistance RL as a low-pass filter.

Cutoff frequency (fc)
$$\approx \frac{1}{2\pi CLRL}$$

Dimensional outlines (unit: mm)

S7183



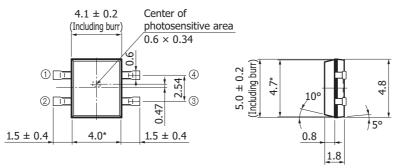
- ① Cathode
- ② Anode

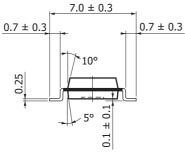
Tolerance unless otherwise noted: ±0.2, ±2° Shaded area indicates burr. Values in parentheses are not guaranteed, but for reference.

Lead surface finish: Silver plating Standard packing: Polyethylene pack [anti-static type] (500 pcs/pack)

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S7184





Pins ② and ④ must be connected to ③ on the PC board.

- ① Cathode
- ② (Anode)
- ③ Anode
- ④ (Anode)

Tolerance unless otherwise noted: ± 0.1 , $\pm 2^{\circ}$ Shaded area indicates burr. Chip position accuracy with respect to the package dimensions marked * $X \le \pm 0.25$, $Y \le \pm 0.25$, $\theta \le \pm 2^{\circ}$

Lead surface finish: Silver plating Standard packing: Stick (50 pcs/stick)

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Operating voltage, output characteristics

Figure 2 shows the photocurrent vs. reverse voltage characteristics (light source: LED) for the measurement circuit example in Figure 1. The output curves are shown for illuminance levels. The output curves rise from a reverse voltage (rising voltage) of approximately $0.7 \text{ V } (\pm 10\%)$.

To protect the photo IC diode from excessive current, a 150 Ω (\pm 20%) protection resistor is inserted in the circuit. Reverse voltage V_R when the photo IC diode is saturated is the sum of Vbe(ON) and the voltage drop across the protection resistor Rin [Equation (1)].

$$V_R = Vbe(ON) + I_L \times Rin \dots (1)$$

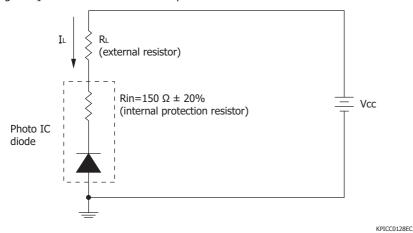
The photodiode's reverse voltage (V_R) is expressed by Equation (2) according to the voltage drop across the external resistor. This is indicated as load lines in Figure 2.

$$V_R = V_{CC} - I_L \times R_L \dots (2)$$

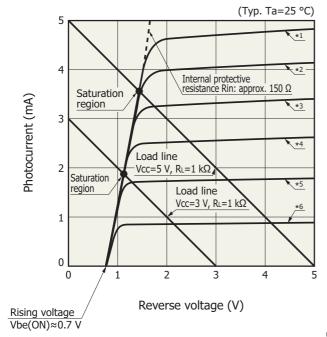
In Figure 2, the intersections between the output curves and the load lines are the saturation points. From these points, the maximum detectable light level can be specified. Since the maximum light level is determined by the supply voltage (Vcc) and load resistance (R_L), adjust them according to the operating conditions.

Note: The temperature characteristics of Vbe(ON) is approximately -2 mV/ $^{\circ}$ C, and that of the protection resistor is approximately 0.1%/ $^{\circ}$ C.

[Figure 1] Measurement circuit example



[Figure 2] Photocurrent vs. reverse voltage



	((Unit: lx)		
Note	S7183	S7184		
*1	480	2660		
*2	410	2270		
*3	340	1880		
*4	260	1440		
*5	180	1000		
*6	90	500		

Related information

www.hamamatsu.com/sp/ssd/doc_en.html

- Precautions
 - · Disclaimer
 - · Surface mount type products

Information described in this material is current as of June 2017.

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